

NPN SILICON EPITAXIAL TRANSISTOR FOR LOW-FREQUENCY POWER AMPLIFIERS AND MID-SPEED SWITCHING

FEATURES

NEC

- Large current capacitance in small dimension: Ic(DC) = 7 A
- Low collector saturation voltage: VCE(sat) = 0.3 V MAX. (Ic = 3.0 A)
- Ideal for use in a lamp driver
- Complementary transistor: 2SA1129

Parameter Symbol Ratings Unit Collector to base voltage Vсво 100 V Collector to emitter voltage VCEO 40 v V Emitter to base voltage 7.0 Vево Collector current (DC) IC(DC) 7.0 А Collector current (pulse) A C(pulse)* 15 3.5 A Base current (DC) B(DC) $P_{T} (T_{c} = 25^{\circ}C)$ Total power dissipation 40 w Total power dissipation P⊤ (T_a = 25°C) 1.5 W °C Junction temperature Tj 150 Tstg -55 to +150 °C Storage temperature

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

* PW \leq 300 μ s, duty cycle \leq 10%

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 40 \text{ V}, \text{ I}_{E} = 0$			10	μA
Emitter cutoff current	Іево	VEB = 5.0 V, Ic = 0			10	μA
DC current gain	h _{FE1}	Vce = 1.0 V, Ic = 3 A*	40		320	
DC current gain	hFE2	Vce = 1.0 V, Ic = 5 A*	20			
Collector saturation voltage	VCE(sat)1	Ic = 3.0 A, I _B = 0.1 A*			0.3	V
Base saturation voltage	V _{BE(sat)1}	Ic = 3.0 A, I _B = 0.1 A*			1.5	V
Collector saturation voltage	VCE(sat)2	Ic = 5.0 A, I _B = 0.5 A*			0.6	V
Base saturation voltage	V _{BE(sat)2}	Ic = 5.0 A, I _B = 0.5 A*			2.0	V
Turn-on time	ton	Ic = 5.0 A, Iв1 = -Iв2 = 0.5 A			1.0	μs
Storage time	tstg	R_L = 4.0 Ω, Vcc ≅ 20 V PW ≅ 50 μs, duty cycle ≤ 2 %			2.5	μs
Fall time	tr				1.0	μs

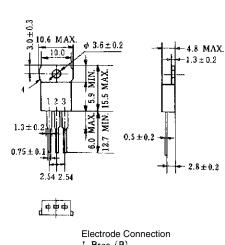
* Pulse test PW \leq 350 μ s, duty cycle \leq 2%

hFE1 classification M: 40 to 80, L: 60 to 120, K: 100 to 200, J: 160 to 320

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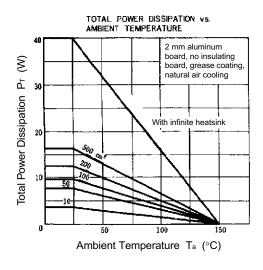
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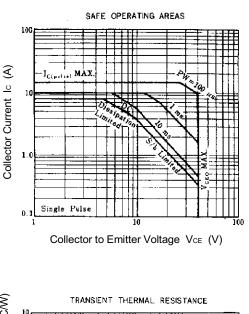
PACKAGE DRAWING (UNIT: mm)

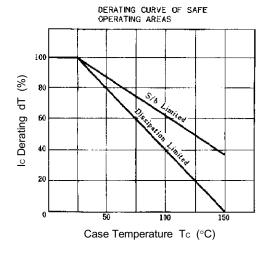


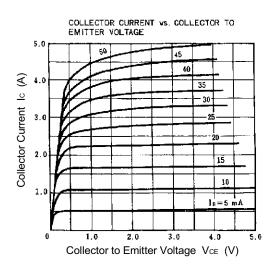


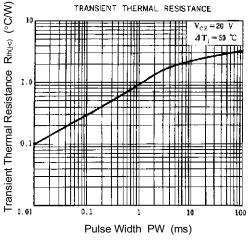
TYPICAL CHARACTERISTICS (Ta = 25°C)

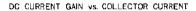


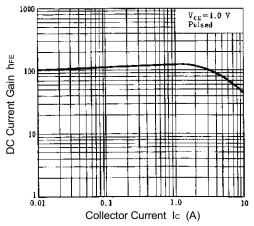


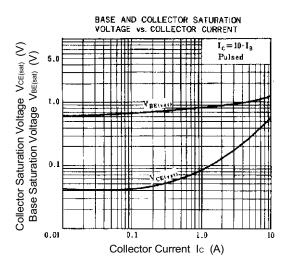




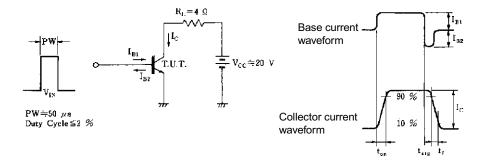








SWITCHING TIME (t_on, t_stg, t_f) TEST CIRCUIT



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